

# isc Silicon NPN Power Transistors

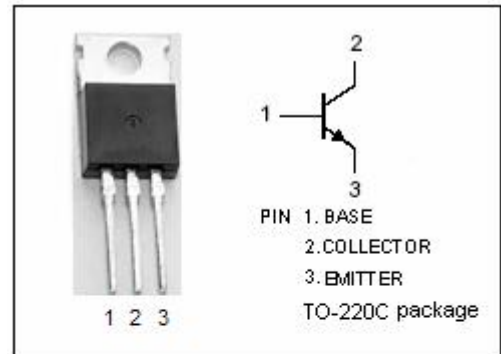
# MJE13070/13071

## DESCRIPTION

- Collector-Emitter Sustaining Voltage-  
:  $V_{CE(SUS)} = 400V(\text{Min})$ - MJE13070  
=  $450V(\text{Min})$ - MJE13071
- Collector-Emitter Saturation Voltage-  
:  $V_{CE(sat)} = 3.0V(\text{Min})@I_C = 5A$
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

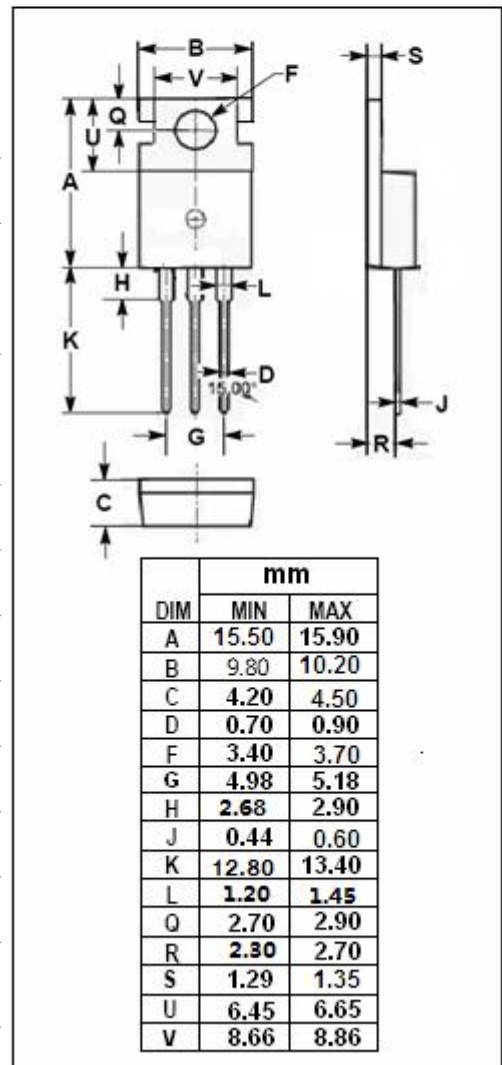
## APPLICATIONS

- Designed for high-voltage, high-speed, power switching in inductive circuits, where fall time is critical. They are particularly suited for line-operated switchmode applications such as switching regulators, inverters, DC-DC converter, motor controls, solenoid drive and deflection circuits.



## ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT	
$V_{CBO}$	Collector- Base Voltage	MJE13070	650	V
		MJE13071	750	
$V_{CEO}$	Collector-Emitter Voltage	MJE13070	400	V
		MJE13071	450	
$V_{EBO}$	Emitter-Base Voltage	6	V	
$I_C$	Collector Current-Continuous	5	A	
$I_{CM}$	Collector Current-Peak	8	A	
$I_B$	Base Current	2	A	
$P_C$	Collector Power Dissipation @ $T_C=25^\circ\text{C}$	80	W	
$T_J$	Junction Temperature	150	$^\circ\text{C}$	
$T_{stg}$	Storage Temperature Range	-65~150	$^\circ\text{C}$	



## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	1.56	$^\circ\text{C/W}$

**isc Silicon NPN Power Transistors**
**MJE13070/13071**
**ELECTRICAL CHARACTERISTICS**
 $T_C=25^{\circ}\text{C}$  unless otherwise specified

SYMBOL	PARAMETER		CONDITIONS	MIN	MAX	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	MJE13070	$I_C=50\text{mA}; I_B=0$	400		V
		MJE13071				
$V_{CE(sat)-1}$	Collector-Emitter Saturation Voltage		$I_C=3\text{A}; I_B=0.6\text{A}$ $I_C=3\text{A}; I_B=0.6\text{A}; T_C=100^{\circ}\text{C}$		1.0 2.0	V
$V_{CE(sat)-2}$	Collector-Emitter Saturation Voltage		$I_C=5\text{A}; I_B=1\text{A}$		3.0	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage		$I_C=3\text{A}; I_B=0.6\text{A}$ $I_C=3\text{A}; I_B=0.6\text{A}; T_C=100^{\circ}\text{C}$		1.5 1.5	V
$I_{CBO}$	Collector Cutoff Current		$V_{CB}=\text{Rated Value}; I_E=0$ $V_{CB}=\text{Rated Value}; I_E=0; T_C=100^{\circ}\text{C}$		0.5 2.5	mA
$I_{EBO}$	Emitter Cutoff Current		$V_{EB}=6\text{V}; I_C=0$		1.0	mA
$h_{FE}$	DC Current Gain		$I_C=3\text{A}; V_{CE}=5\text{V}$	8		
$C_{OB}$	Output Capacitance		$I_E=0; V_{CB}=10\text{V}; f_{\text{test}}=1.0\text{kHz}$	100		pF

**Switching Times**

$t_d$	Delay Time	$I_C=3\text{A}; I_{B1}=0.4\text{A}; V_{BE(\text{off})}=5\text{V};$ $V_{CC}=250\text{V}; t_p=30\mu\text{s}; \text{Duty Cycle} \leq 1\%$		0.05	$\mu\text{s}$
$t_r$	Rise Time			0.4	$\mu\text{s}$
$t_{stg}$	Storage Time			1.5	$\mu\text{s}$
$t_f$	Fall Time			0.5	$\mu\text{s}$

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